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D45E Series

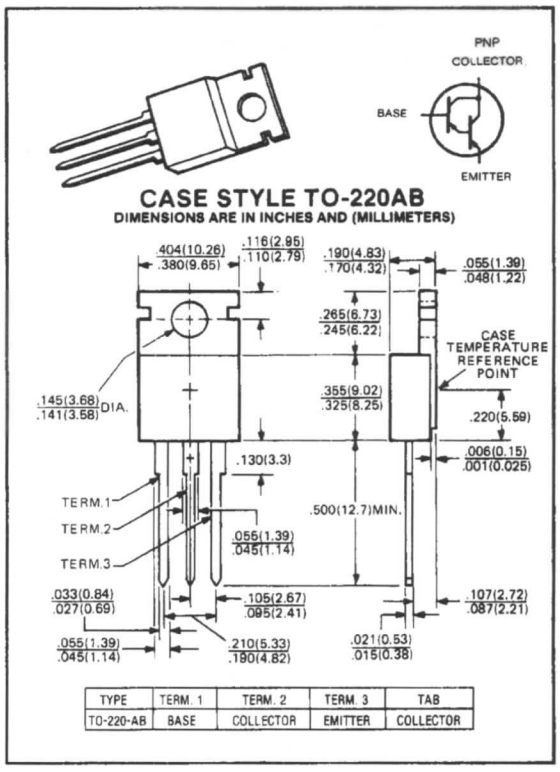
-40 - (-80) VOLTS
-10 AMP, 50 WATTS

VERY HIGH GAIN PNP POWER DARLINGTON TRANSISTORS

COMPLEMENTARY TO THE D44E SERIES

Applications:

- Driver
- Regulator
- Capacitor Multiplier
- Solenoid Driver
- Inverter Power Supply
- Switch
- Audio Output
- Relay Substitute
- Oscillator
- Servo-Amplifier



maximum ratings (T_A = 25°C) (unless otherwise specified)

RATING	SYMBOL	D45E1	D45E2	D45E3	UNITS
Collector-Emitter Voltage	V_{CEO}	-40	-60	-80	Volts
Collector-Emitter Voltage	V_{CES}	-40	-60	-80	Volts
Emitter Base Voltage	V_{EBO}	-7	-7	-7	Volts
Collector Current — Continuous Peak(1)	I_C I_{CM}	-10 -20	-10 -20	-10 -20	A
Base Current — Continuous	I_B	-1	-1	-1	A
Total Power Dissipation @ T_A = 25°C @ T_C = 25°C	P_D	1.67 50	1.67 50	1.67 50	Watts
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-55 to +150	-55 to +150	-55 to +150	°C

thermal characteristics

Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	75	75	75	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.5	2.5	2.5	°C/W
Maximum Lead Temperature for Soldering Purposes: ⅛" from Case for 5 Seconds	T_L	260	260	260	°C

(1) Pulse Test: Pulse Width = 300ms. Duty Cycle ≤ 2%.

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

electrical characteristics (T_C = 25°C) (unless otherwise specified)

CHARACTERISTIC		SYMBOL	MIN	TYP	MAX	UNIT
off characteristics[1]						
Collector-Emitter Voltage (I_C = -100mA)	D45E1	V_{CEO}	-40	—	—	Volts
	D45E2		-60	—	—	
	D45E3		-80	—	—	
Collector Cut-off Current (V_{CE} = Rated V_{CES})		I_{CES}	—	—	-10	μA
Emitter Cutoff Current (V_{EB} = -7V)		I_{EBO}	—	—	-1.0	μA
second breakdown						
Second Breakdown with Base Forward Biased		FBSOA	SEE FIGURE 6			
on characteristics						
DC Current Gain (I_C = -5A, V_{CE} = -5V)		h_{FE}	1,000	—	—	—
Collector-Emitter Saturation Voltage (I_C = -5.0A, I_B = -10mA)		$V_{CE(sat)}$	—	—	-1.5	V
(I_C = -10.0A, I_B = -20mA)			—	—	-2.0	V
Base-Emitter Saturation Voltage (I_C = -5.0A, I_B = -10mA)		$V_{BE(sat)}$	—	—	-2.5	Volts
dynamic characteristics						
Collector Capacitance (V_{CE} = -10V, f = 1MHz)		C_{CBO}	—	—	220	pF
switching characteristics						
Resistive Load						
Delay Time + Rise Time	I_C = -10A, I_{B1} = I_{B2} = -20mA	$t_d + t_r$	—	0.6	—	μS
Storage Time	V_{CC} = -40V, t_p = 25μsec	t_s	—	2.0	—	
Fall Time		t_f	—	0.5	—	

(1) Pulse Test: PW ≤ 300ms Duty Cycle ≤ 2%.

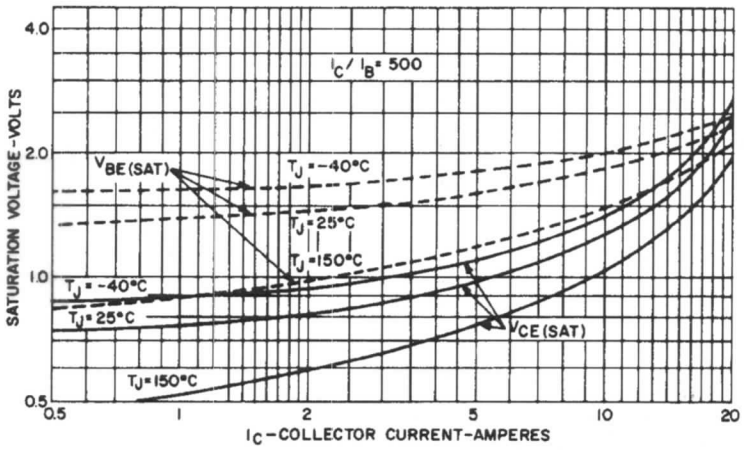


FIG. 1 TYPICAL SATURATION VOLTAGE CHARACTERISTICS